NSN 5961-01-169-6510

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-169-6510 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.107 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.022 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 on-state voltage, peak **Current Rating Per Characteristic:** 4.70 milliamperes all primaries pascal **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Test Features:** Tested per base ten systems dwg 21915 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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